

# HN27128AG Series

## 16384-word X 8-bit UV Erasable and Programmable ROM

The HN27128AG is a 16384-word by 8-bit erasable and electrically programmable ROM. This device is packaged in a 28-pin, dual-in-line package with transparent window. The transparent window allows the user to expose the chip to ultraviolet light to erase the bit pattern, whereby a new pattern can then be written into the device.

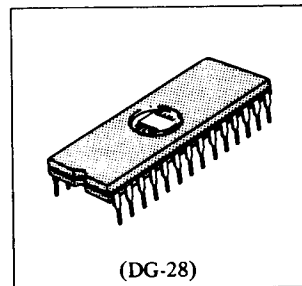
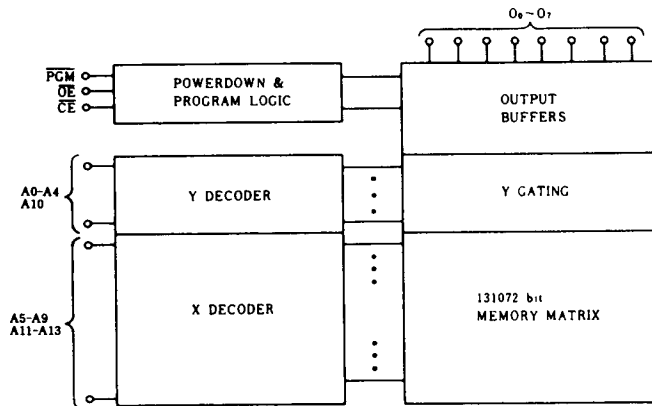
### ■ FEATURES

- Single Power Supply . . . . . +5V ±5%
- High Performance . . . . . Program Voltage: +12.5V D.C. Programming  
High Performance Programming Operations
- Static . . . . . No Clocks Required
- Inputs and Outputs TTL Compatible During Both Read and Program Modes
- Access Time . . . . . 170/200/250/300ns(max.)
- Absolute Max. Rating of . . . . . 14.0V Max.  
V<sub>pp</sub> pin
- Low Stand-by Current . . . . . 35mA Max. (stand-by)
- Device Identifier Mode . . . . . Manufacturer Code and Device Code

### ■ ORDERING INFORMATION

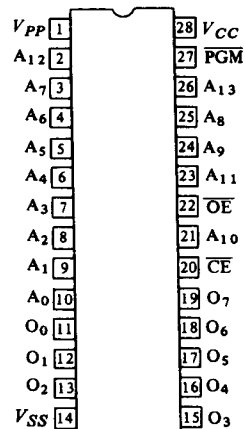
Type No.	Access Time	Package
HN27128AG-17	170ns	600 mil 28 pin Cerdip
HN27128AG-20	200ns	
HN27128AG-25	250ns	
HN27128AG-30	300ns	

### ■ BLOCK DIAGRAM



(DG-28)

### ■ PIN ARRANGEMENT



(Top View)



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## ■ MODE SELECTION

MODE	Pins CE (20)	OE (22)	PGM (27)	A9 (24)	V <sub>PP</sub> (1)	V <sub>CC</sub> (28)	Outputs (11 – 13, 15 – 19)
Read	V <sub>IL</sub>	V <sub>IL</sub>	V <sub>IH</sub>	X	V <sub>CC</sub>	V <sub>CC</sub>	Dout
Output Disable	V <sub>IL</sub>	V <sub>IH</sub>	V <sub>IH</sub>	X	V <sub>CC</sub>	V <sub>CC</sub>	High Z
Standby	V <sub>IH</sub>	X	X	X	V <sub>CC</sub>	V <sub>CC</sub>	High Z
High Performance Program	V <sub>IL</sub>	X	V <sub>IL</sub>	X	V <sub>PP</sub>	V <sub>CC</sub>	Din
Program Verify	V <sub>IL</sub>	V <sub>IL</sub>	V <sub>IH</sub>	X	V <sub>PP</sub>	V <sub>CC</sub>	Dout
Program Inhibit	V <sub>IH</sub>	X	X	X	V <sub>PP</sub>	V <sub>CC</sub>	High Z
Identifier	V <sub>IL</sub>	V <sub>IL</sub>	V <sub>IH</sub>	V <sub>H</sub> *2	V <sub>CC</sub>	V <sub>CC</sub>	Code

Note) \*1. X . . . Don't care

\*2. V<sub>H</sub> = 12.0V ±0.5V

## ■ ABSOLUTE MAXIMUM RATINGS

Item	Symbol	Value	Unit
Operating Temperature Range	T <sub>opr</sub>	0 to +70	°C
Storage Temperature Range	T <sub>stg</sub>	-65 to +125	°C
Storage Temperature Range Under Bias	T <sub>bias</sub>	-10 to +80	°C
Voltage on Pin 24 (A9)*1	V <sub>ID</sub>	-0.6 to +13.5	V
All Input and Output Voltages*1	V <sub>IN</sub> , V <sub>out</sub>	-0.6 to +7	V
V <sub>PP</sub> Voltage*1	V <sub>PP</sub>	-0.6 to +14.0	V
V <sub>CC</sub> Voltage*1	V <sub>CC</sub>	-0.6 to +7	V

Note) \*1. With respect to V<sub>SS</sub>

## ■ READ OPERATION

### ● DC AND OPERATING CHARACTERISTICS (T<sub>a</sub> = 0 to 70°C, V<sub>CC</sub> = 5V ±5%, V<sub>PP</sub> = V<sub>CC</sub>)

Parameter	Symbol	Test Conditions	min.	typ.	max.	Unit
Input Leakage Current	I <sub>LI</sub>	V <sub>IN</sub> = 5.25V	-	-	10	μA
Output Leakage Current	I <sub>LO</sub>	V <sub>out</sub> = 5.25V/0.45V	-	-	10	μA
V <sub>PP</sub> Current	I <sub>PP1</sub>	V <sub>PP</sub> = 5.25V	-	-	5	mA
V <sub>CC</sub> Current (Standby)	I <sub>CC1</sub>	CE = V <sub>IH</sub>	-	-	35	mA
V <sub>CC</sub> Current (Active)	I <sub>CC2</sub>	CE = OE = V <sub>IL</sub>	-	40	100	mA
Input Low voltage	V <sub>IL</sub>		-0.1*1	-	0.8	V
Input High Voltage	V <sub>IH</sub>		2.0	-	V <sub>CC</sub> +1*2	V
Output Low Voltage	V <sub>OL</sub>	I <sub>OL</sub> = 2.1mA	-	-	0.45	V
Output High Voltage	V <sub>OH</sub>	I <sub>OH</sub> = -400μA	2.4	-	-	V

Notes) \*1. -0.6V for pulse width ≤ 20ns

\*2. V<sub>CC</sub> + 1.5V for pulse width ≤ 20ns. If V<sub>IH</sub> is over the specified maximum value, read operation cannot be guaranteed.



● AC CHARACTERISTICS ( $T_a = 0$  to  $+70^\circ\text{C}$ ,  $V_{CC}=5\text{V} \pm 5\%$ ,  $V_{PP} = V_{CC}$ )

Parameter	Symbol	Test Condition	HN27128AG-17		HN27128AG-20		HN27128AG-25		HN27128AG-30		Unit
			min.	max.	min.	max.	min.	max.	min.	max.	
Address to Output Delay	$t_{ACC}$	$\overline{CE}=\overline{OE}=V_{IL}$	-	170	-	200	-	250	-	300	ns
$\overline{CE}$ to Output Delay	$t_{CE}$	$\overline{OE}=V_{IL}$	-	170	-	200	-	250	-	300	ns
$\overline{OE}$ to Output Delay	$t_{OE}$	$\overline{CE}=V_{IL}$	-	75	-	75	-	100	-	120	ns
$\overline{OE}$ High Output Float	$t_{DF}$	$\overline{CE}=V_{IL}$	0	55	0	55	0	60	0	105	ns
Address to Output Hold	$t_{OH}$	$\overline{CE}=\overline{OE}=V_{IL}$	0	-	0	-	0	-	0	-	ns

Note:  $t_{DF}$  defines the time at which the Output achieves the open circuit condition and Data is no longer driven.

● SWITCHING CHARACTERISTICS

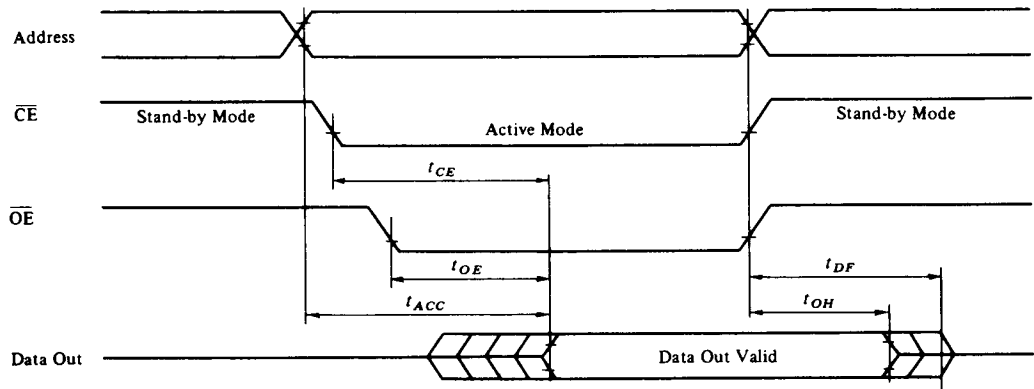
Test Condition

Input Pulse Levels: 0.45V to 2.4V

Input Rise and Fall Time:  $\leq 20\text{ns}$

Output Load: 1 TTL Gate +100pF

Reference Level for Measuring Timing: 0.8V and 2.0V



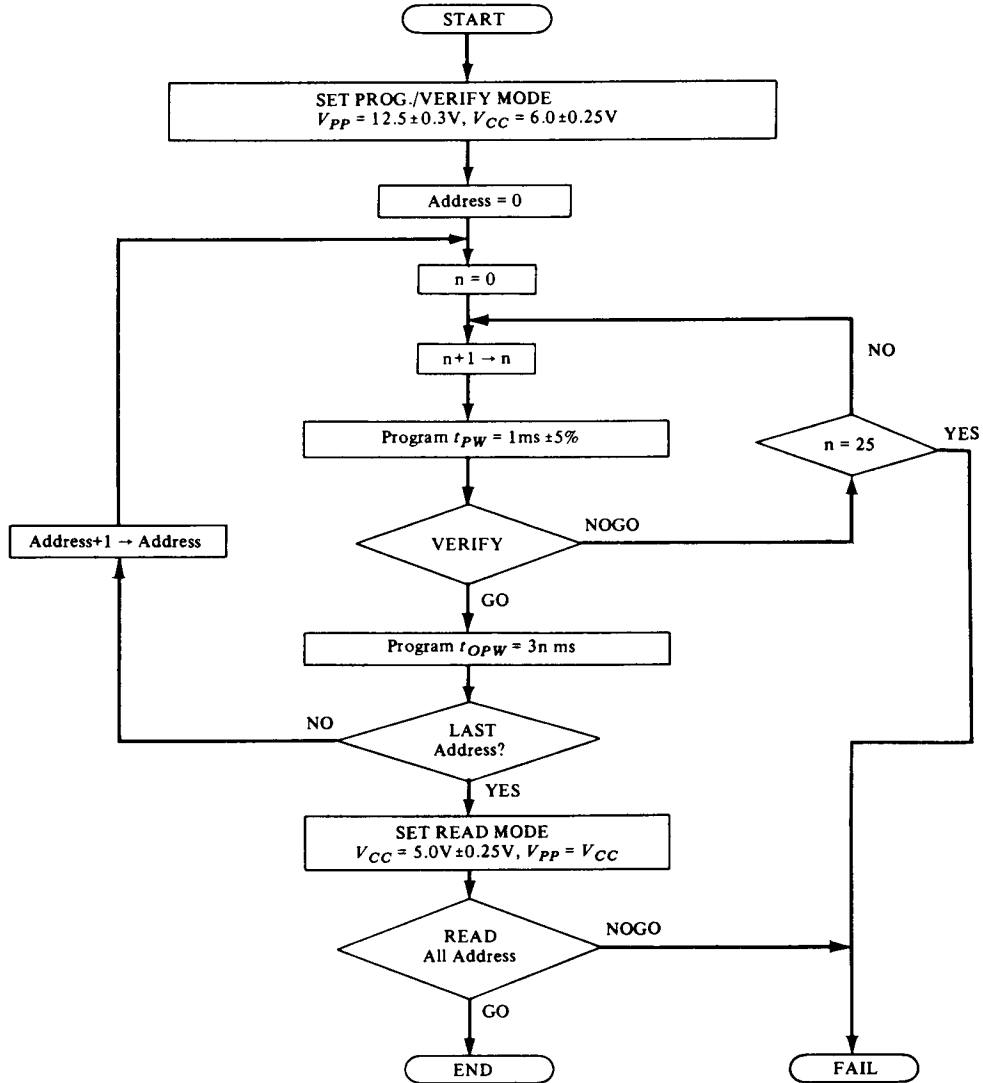
● CAPACITANCE ( $T_a = 25^\circ\text{C}$ ,  $f = 1\text{MHz}$ )

Parameter	Symbol	Test Condition	min.	typ.	max.	Unit
Input Capacitance	$C_{in}$	$V_{in} = 0\text{V}$	-	4	6	pF
Output Capacitance	$C_{out}$	$V_{out} = 0\text{V}$	-	8	12	pF



■ HIGH PERFORMANCE PROGRAMMING

This device can be applied the High Performance Programming algorithm shown in following flowchart. This algorithm allows to obtain faster programming time without any voltage stress to the device nor deterioration in reliability of programmed data.



High Performance Programming Flowchart



## ■ HIGH PERFORMANCE PROGRAMMING OPERATION

### ● DC PROGRAMMING CHARACTERISTICS ( $T_a = 25^\circ\text{C} \pm 5^\circ\text{C}$ , $V_{CC} = 6\text{V} \pm 0.25\text{V}$ , $V_{PP} = 12.5\text{V} \pm 0.3\text{V}$ )

Parameter	Symbol	Test Condition	min.	typ.	max.	Unit
Input Leakage Current	$I_{LI}$	$V_{IN} = 5.25\text{V}$	–	–	10	$\mu\text{A}$
Output Low Voltage During Verify	$V_{OL}$	$I_{OL} = 2.1\text{mA}$	–	–	0.45	V
Output High Voltage During Verify	$V_{OH}$	$I_{OH} = -400\mu\text{A}$	2.4	–	–	V
$V_{CC}$ Current (Active)	$I_{CC2}$		–	–	100	mA
Input Low Level	$V_{IL}$		-0.1*1	–	0.8	V
Input High Level	$V_{IH}$		2.0	–	$V_{CC} + 0.5$ *2	V
$V_{PP}$ Supply Current	$I_{PP2}$	$\overline{\text{CE}} = \text{PGM} = V_{IL}$	–	–	50	mA

Notes) \*1. -6.0V for pulse width  $\leq 20\text{ns}$ .

\*2. If  $V_{IH}$  is over the specified maximum value, programming operation cannot be guaranteed.

### ● AC PROGRAMMING CHARACTERISTICS ( $T_a = 25^\circ\text{C} \pm 5^\circ\text{C}$ , $V_{CC} = 6\text{V} \pm 0.25\text{V}$ , $V_{PP} = 12.5\text{V} \pm 0.3\text{V}$ )

Parameter	Symbol	Test Condition	min.	typ.	max.	Unit
Address Setup Time	$t_{AS}$		2	–	–	$\mu\text{s}$
$\overline{\text{OE}}$ Setup Time	$t_{OES}$		2	–	–	$\mu\text{s}$
Data Setup Time	$t_{DS}$		2	–	–	$\mu\text{s}$
Address Hold Time	$t_{AH}$		0	–	–	$\mu\text{s}$
Data Hold Time	$t_{DH}$		2	–	–	$\mu\text{s}$
$\overline{\text{OE}}$ to Output Float Delay	$t_{DF}$ *1		0	–	130	ns
$V_{PP}$ Setup Time	$t_{VPS}$		2	–	–	$\mu\text{s}$
$V_{CC}$ Setup Time	$t_{VCS}$		2	–	–	$\mu\text{s}$
PGM Pulse Width During Initial Programming	$t_{PW}$		0.95	1.0	1.05	ms
PGM Pulse Width During Overprogramming	$t_{OPW}$ *2		2.85	–	78.75	ms
$\overline{\text{CE}}$ Setup Time	$t_{CES}$		2	–	–	$\mu\text{s}$
Data Valid from $\overline{\text{OE}}$	$t_{OE}$		–	–	150	ns

Notes) \*1.  $t_{DF}$  defines the time at which the output achieves the open circuit condition and data is no longer driven.

\*2.  $t_{OPW}$  is defined as mentioned in flow chart.



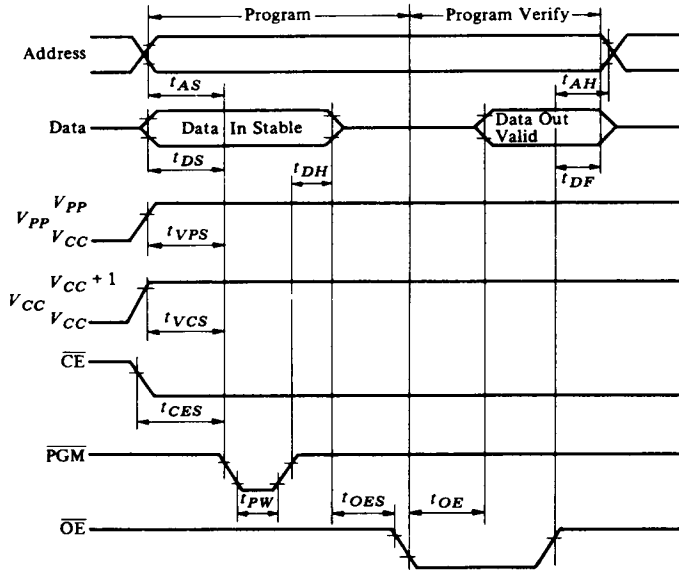
● SWITCHING CHARACTERISTICS

Test Condition

Input Pulse Level: 0.45V to 2.4V

Input Rise and Fall Time:  $\leq 20\text{ns}$

Reference Level for Measuring Timing: 0.8V and 2.0V



■ ERASE

Erasure of HN27128AG is performed by exposure to ultraviolet light of 2537Å and all the output data are changed to "1" after this erasure procedure. The minimum integrated dose (i.e. UV intensity x exposure time) for erasure is 15 W.sec/cm<sup>2</sup>.

■ DEVICE IDENTIFIER MODE

The Identifier Mode allows the reading out of binary codes that identify manufacturer and type of device, from outputs of EPROM. By this Mode, the device will be automatically matched its own corresponding programming algorithm, using programming equipment.

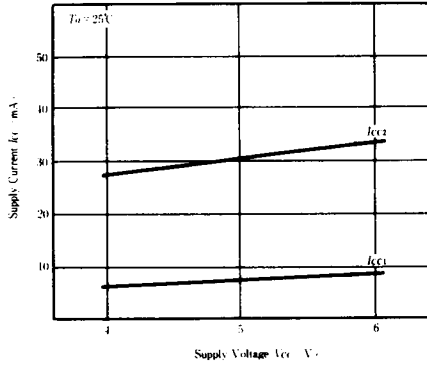
● HN27128AG SERIES IDENTIFIER CODE

Pins	A <sub>0</sub>	O <sub>7</sub>	O <sub>6</sub>	O <sub>5</sub>	O <sub>4</sub>	O <sub>3</sub>	O <sub>2</sub>	O <sub>1</sub>	O <sub>0</sub>	Hex Data
Identifier	(10)	(19)	(18)	(17)	(16)	(15)	(13)	(12)	(11)	
Manufacturer Code	V <sub>IL</sub>	0	0	0	0	0	1	1	1	07
Device Code	V <sub>IH</sub>	0	0	0	0	1	1	0	1	0D

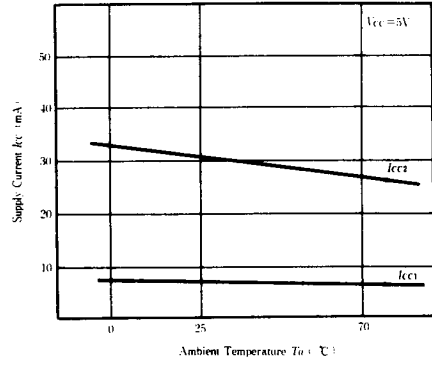
- Notes: 1. A<sub>9</sub> = 12.0V ± 0.5V  
 2. A<sub>1</sub> - A<sub>8</sub>, A<sub>10</sub> - A<sub>19</sub>,  $\overline{\text{CE}}$ ,  $\overline{\text{OE}}$  = V<sub>IL</sub>, PGM = V<sub>IH</sub>.



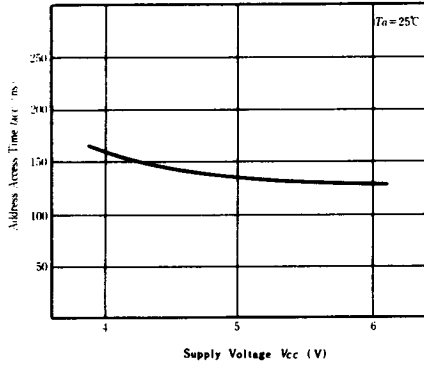
**SUPPLY CURRENT VS. SUPPLY VOLTAGE**



**SUPPLY CURRENT VS. AMBIENT TEMPERATURE**



**ADDRESS ACCESS TIME VS. SUPPLY VOLTAGE**



**ADDRESS ACCESS TIME VS. AMBIENT TEMPERATURE**

